

Features

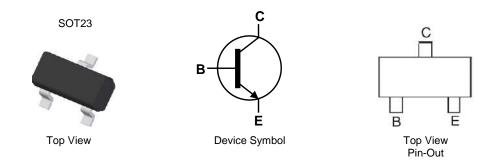
- BVCEO > 100V
- Ic = 2.5A Collector Current
- Low Saturation Voltage VCE(sat) < 95mV @ 1A
- Complementary PNP Part: ZXTP25100DFH
- **Epitaxial Planar Die Construction**
- High Gain
- $R_{CE(sat)} = 80m\Omega$
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (03)
- Weight: 0.008 grams (Approximate)

Applications

- **DC-DC** converters
- DC fans
- Motor controls
- Lamps, relays and solenoid driving



Ordering Information (Note 4)

Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing		
Fait Nulliper	гаскауе	Warking	Reel Size (Inches)	rape width (mm)	Qty.	Carrier	
ZXTN25100DFHTA	SOT23	1B5	7	8	3,000	Reel	
ZXTN25100DFHTA SOT23 1B5 7 8 3,000 Reel Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Reel							

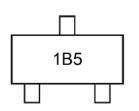
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



1B5 = Product Type Marking Code



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vсво	180	V
Collector-Emitter Voltage	Vceo	100	V
Emitter-Base Voltage	Vebo	7	V
Collector-Emitter Voltage (Forward Blocking)	VCEX	180	V
Emitter-Collector Voltage (Reverse Blocking)	VECO	6	V
Base Current	Ів	0.5	A
Continuous Collector Current	Ic	2.5	A
Peak Collector Current	I _{CM}	3	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		0.73 5.84		
Power Dissipation	(Note 6)		1.05 8.4	w	
Linear Derating Factor	(Note 7)	- P _D -	1.25 9.6	mW/°C	
	(Note 8)		1.81 14.5		
	(Note 5)		171		
Thermal Desistance, lunction to Archiest	(Note 6)		119	*CAM	
Thermal Resistance, Junction to Ambient	(Note 7)	Reja	100	°C/W	
	(Note 8)		69		
Thermal Resistance, Junction to Case	(Note 9)	Rejc	13	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C		

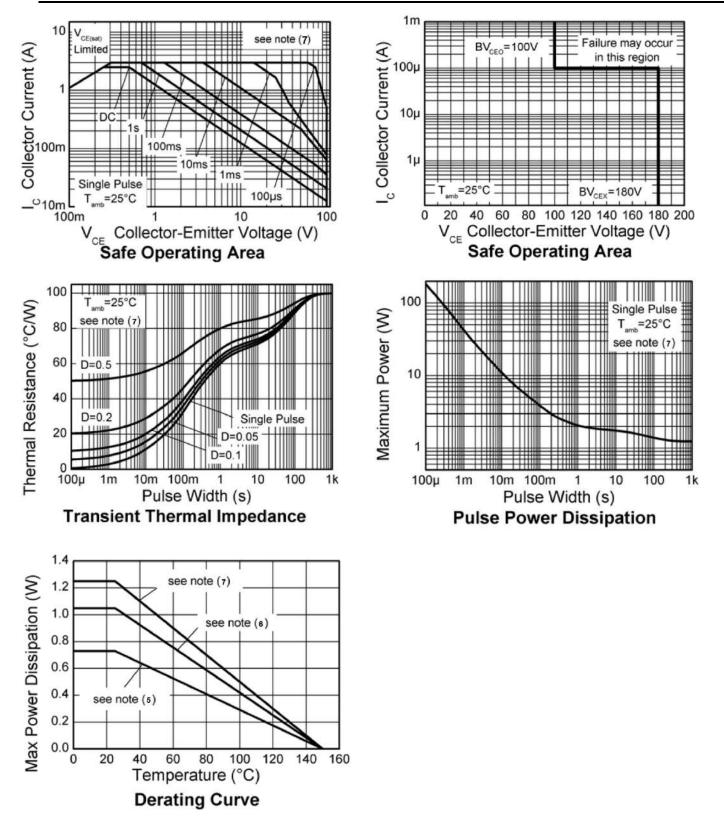
Notes:

5. For the device mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
6. For the device mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions.
7. For the device mounted on 50mm x 50mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions.
8. Same as Note 7, except measured at t < 5 seconds.
9. For the device mounted on minimum recommended people and levent FR4 PCP with high coverage of single sided 4oz copper, in still air conditions.

9. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.



Thermal Characteristics





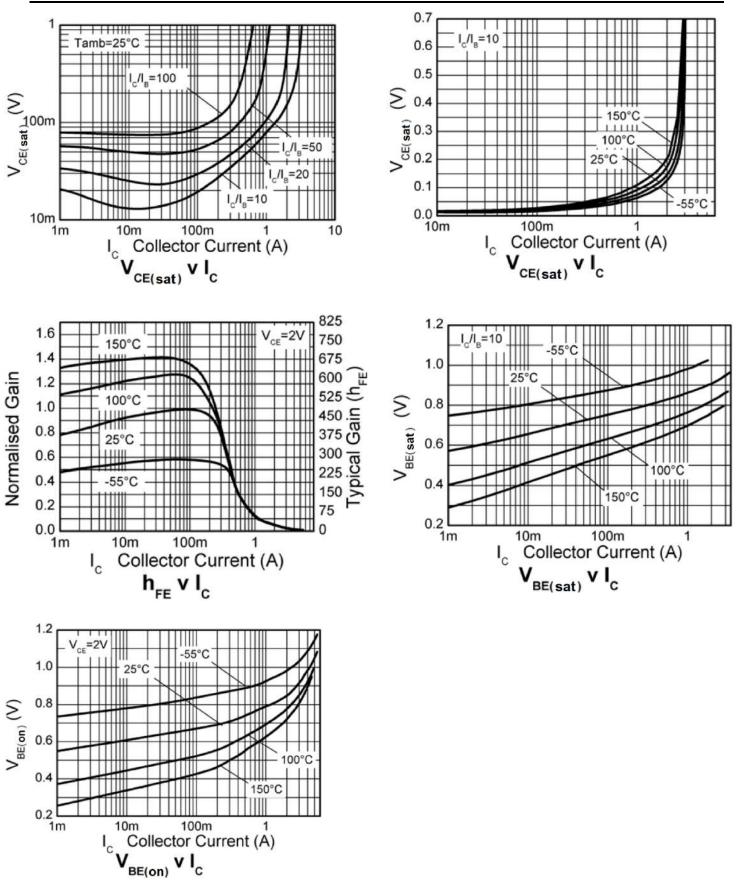
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition	
OFF CHARACTERISTICS				•		·	
Collector-Base Breakdown Voltage	ВУсво	180	220		V	Ic = 100μA	
Collector-Emitter Breakdown Voltage (Note 10)	BVCEO	100	130		V	Ic = 10mA	
Emitter-Base Breakdown Voltage	BVEBO	7.0	8.3	_	V	IE = 100μA	
Emitter-Collector Breakdown Voltage	BVECO	6.0	8.7	_	V	I _E = 100μA	
Emitter-Collector Breakdown Voltage	BVECX	6.0	8.2	—	V	I _E = 100µA, R _{BC} ≤ 1kΩ or -0.25V < V _{BC} < 0.25V	
Collector-Emitter Breakdown Voltage	BVCEX	180	220	—	V	I_C = 100µA, R_{BE} ≤ 1kΩ or -1V < V _{BE} < 0.25V	
Collector Cutoff Current	lana	_	1	50	nA	V _{CB} = 180V	
	Ісво	_	—	0.5	μA	$V_{CB} = 180V, T_{amb} = +100^{\circ}C$	
Emitter Cutoff Current	IEBO	_	1	50	nA	V _{EB} = 5.6V	
Collector-Emitter Cutoff Current	ICEX	—	—	100	nA	V _{CE} = 144V, R _{BE} ≤ 1kΩ or -1V < V _{BE} < 0.25V	
ON CHARACTERISTICS (Note 10)							
		300	450	900		$I_C = 10 mA$, $V_{CE} = 2V$	
DC Current Gain	bee	120	170			Ic = 0.5A, Vce = 2V	
	hFE	40	60			$I_C = 1A$, $V_{CE} = 2V$	
			20	—		Ic = 2.5A, Vce = 2V	
		_	120	170	mV	Ic = 0.5A, I _B = 10mA	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	80	95		$I_{C} = 1A, I_{B} = 100mA$	
		_	215	330		$I_{C} = 2.5A, I_{B} = 250mA$	
Base-Emitter Saturation Voltage	VBE(sat)	_	910	1000	mV	Ic = 2.5A, I _B = 250mA	
Base-Emitter Turn-On Voltage	VBE(on)	_	860	950	mV	IC = 2.5A, VCE = 2V	
SMALL SIGNAL CHARACTERISTICS					-	-	
Output Capacitance (Note 10)	Cobo	_	8.7	15	pF	Vсв = 10V, f = 1MHz	
Transition Frequency	f⊤	_	175	—	MHz	$V_{CE} = 10V, I_C = 100mA$ f = 100MHz	
SWITCHING CHARACTERISTICS							
Delay Time	t _d	_	16.4	_	ns		
Rise Time	tr	_	115	_	ns	Vcc = 10V, Ic = 500mA	
Storage Time	ts	_	763	—	ns	$I_{B1} = -I_{B2} = 50 \text{mA}$	
Fall Time	tf	_	158	_	ns		

Note: 10. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



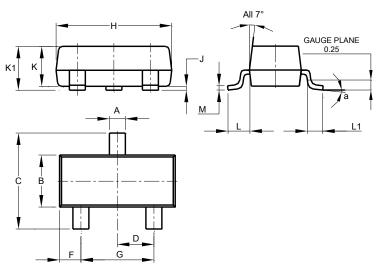
Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

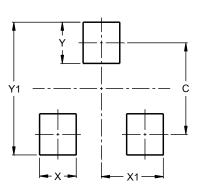
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	0°	8°				
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

SOT23

Dimensions	Value (in mm)			
С	2.0			
Х	0.8			
X1	1.35			
Y	0.9			
Y1	2.9			



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